

Diamond Detector Prototyping

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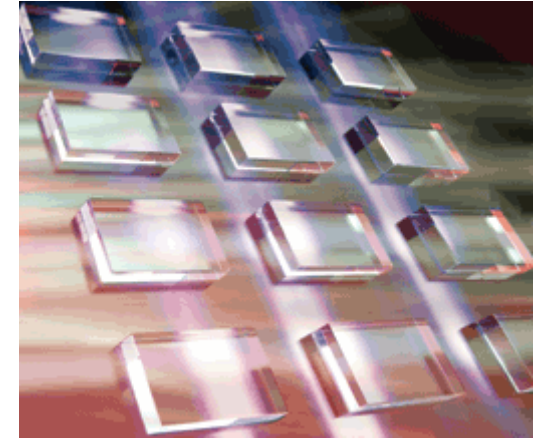


THE UNIVERSITY OF WINNIPEG

Outline: Recipe “how to make a diamond detector”

1. Buy
2. Clean with various acids/bases
3. Metallize
4. Mount in a nice package and wirebond
5. Tests – checks to see if you did a good job
6. Summary

1. Get a “CERN quality diamond from



Chemical Vapour Deposition (CVD) - method of diamond synthesis that can be compared to frost forming on a window – only the process uses carbon rather than water. A mixture of gases is heated to very high temperatures to produce carbon atoms in the form of a plasma. Out of the gases the diamond crystals can grow on complex, 3D shapes – such as tweeter domes

We bought 10.0 x 10.0 x 0.5 mm CVD diamond

2. Boil in various acids/bases (cleaning)

- Main purpose: to remove all organic and inorganic impurities from the diamond surface and replace H on the surface with O.
- The most time consuming process
- Recipe contains boiling in acids/bases for a few minutes @ $\sim 110^{\circ}\text{C}$ in:
 - RCA1 ($\text{NH}_4\text{OH}/\text{H}_2\text{O}_2/\text{H}_2\text{O}$) ratio 1/1/5
 - RCA2 ($\text{HCl}/\text{H}_2\text{O}_2/\text{H}_2\text{O}$) ratio 1/1/5
 - $\text{HCl}/\text{HNO}_3/\text{H}_2\text{O}$ ratio 1/1/1
 - $\text{H}_2\text{SO}_4/\text{H}_2\text{O}_2$ ratio 1/1
 - every time rinse with DI

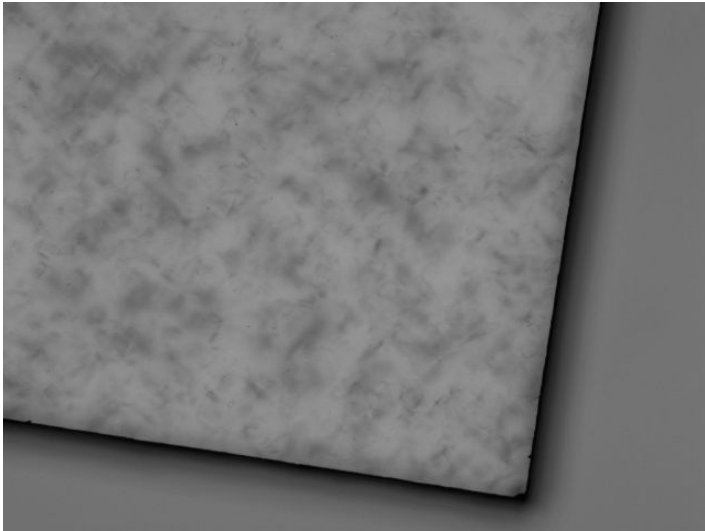
At The University of Manitoba
Nano-Systems Fabrication laboratory



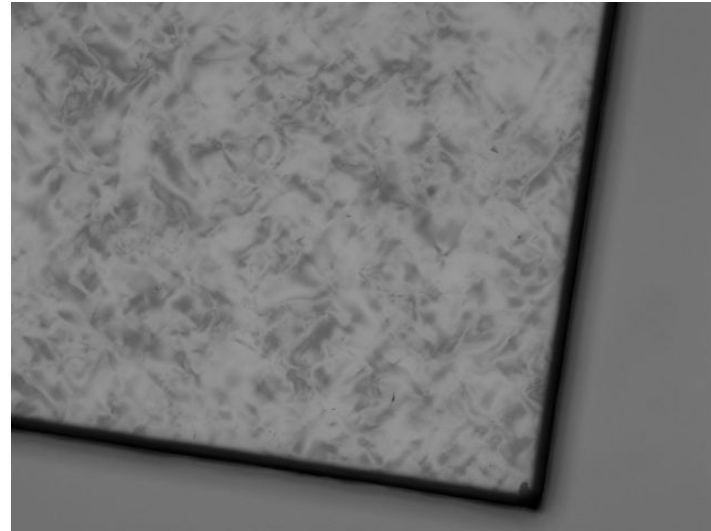
Be careful – things to keep in mind

- Avoid touching diamond with tweezers, To handle sample sapphire or quartz plate should be use, on which diamond is mounted via xtal bond or photoresist.
- To rinse, 2 beakers are used
- No metal tweezers; ceramic or teflon

DIAMOND: Front surface;

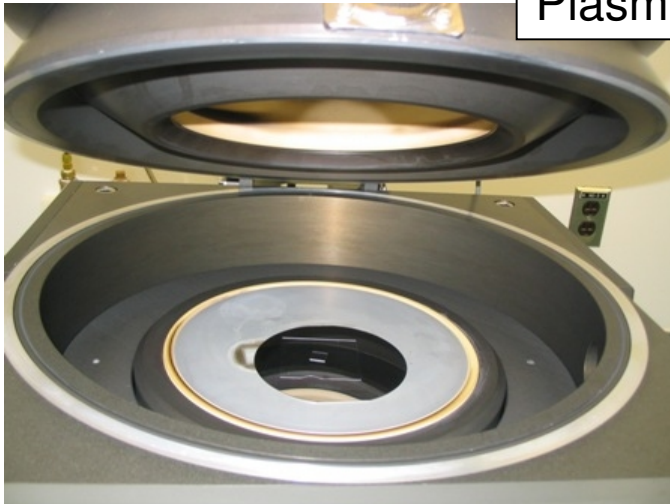
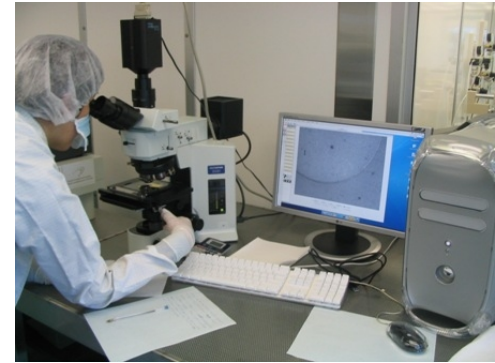


Back surface

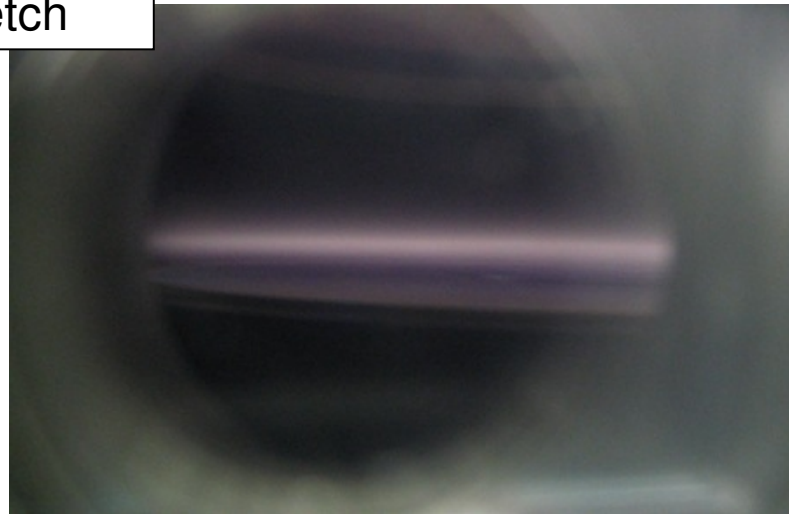


3. Sputter/evaporate on some metal

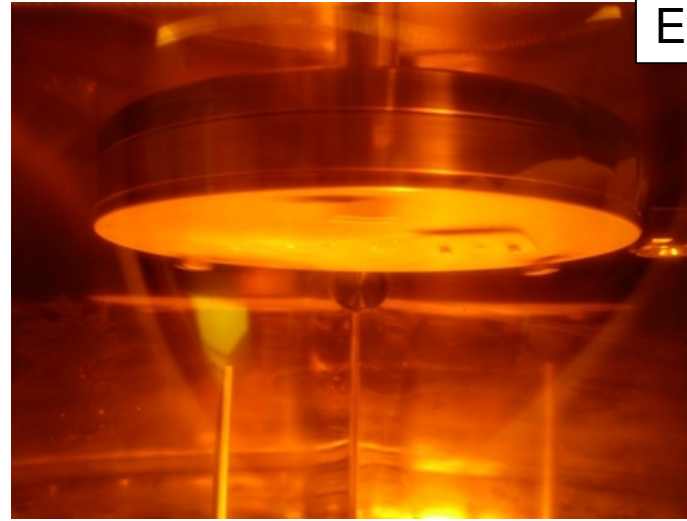
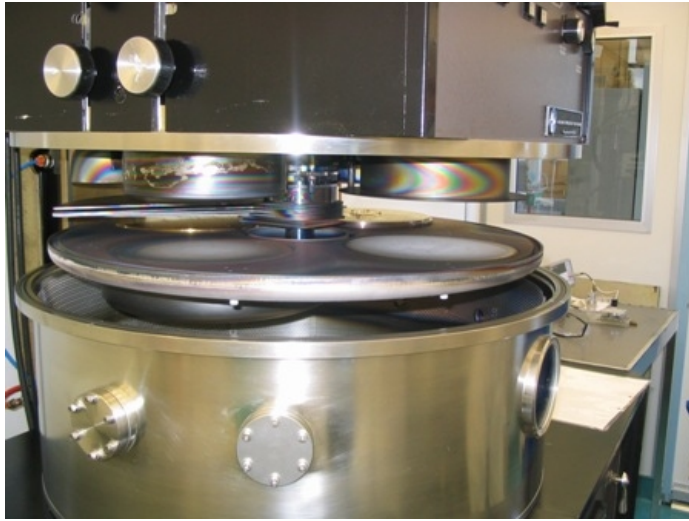
- Purpose: placing the electrodes on each side of diamond
- Two methods:
 - Shadow mask (out of G10 or Al)
 - Photolithography – layer of photoresist
- O₂ Plasma etch
- Cr(500Å)/Au(2000Å), or Ti/Au or Ti/Pt/Au, etc (other recipes)
- Anneal at 400°C



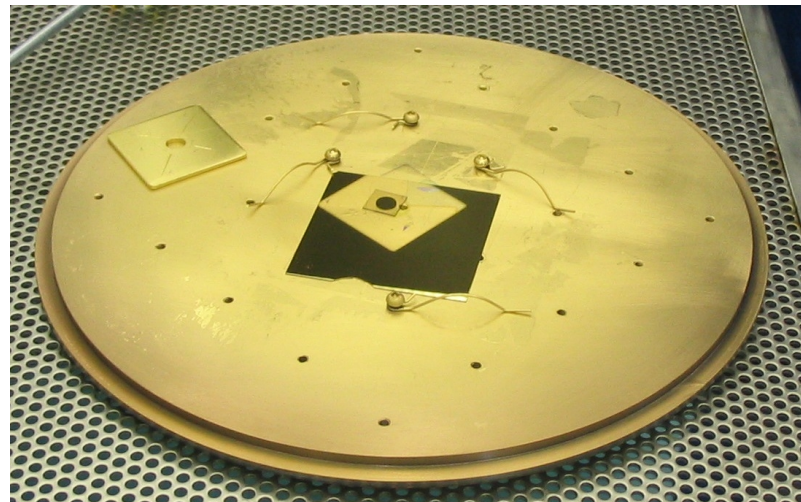
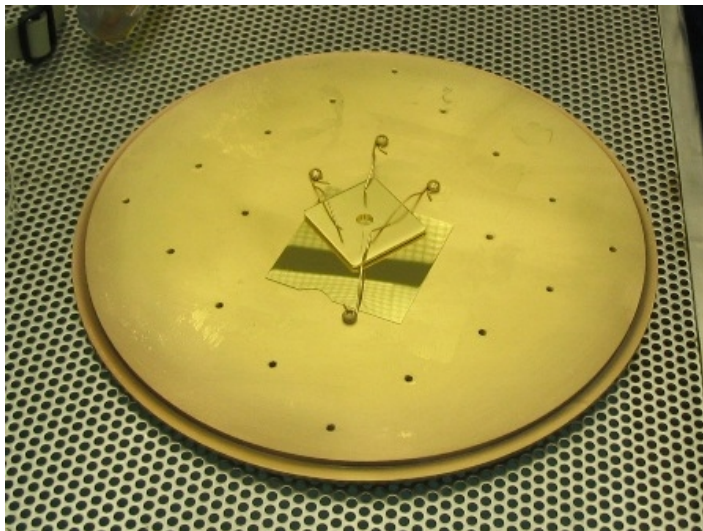
Plasma etch



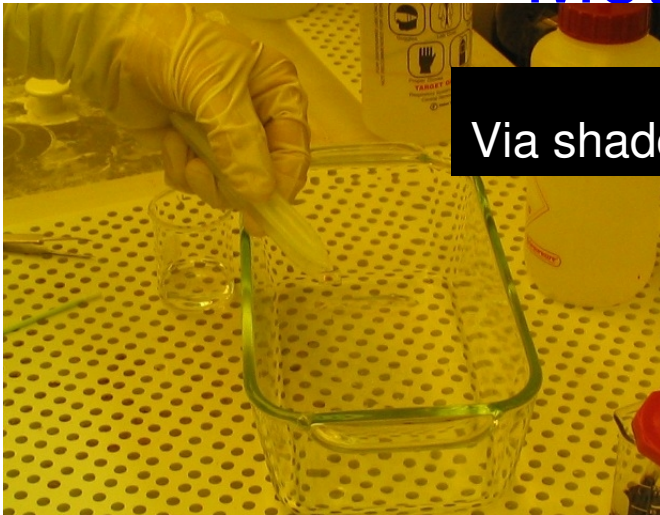
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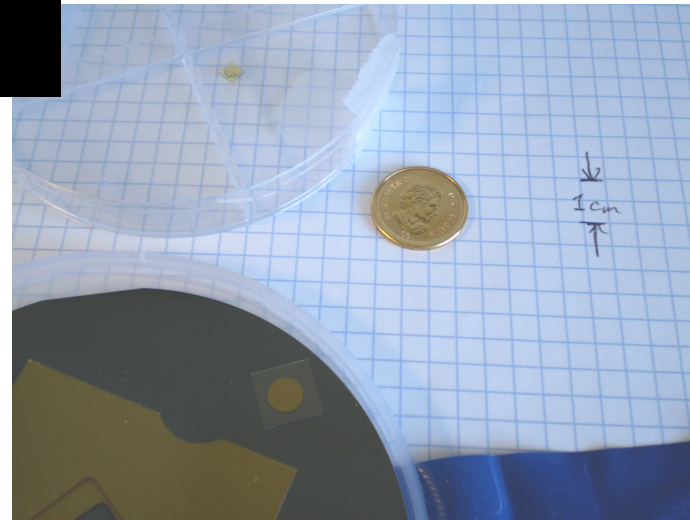
Evaporation



Metallization Results

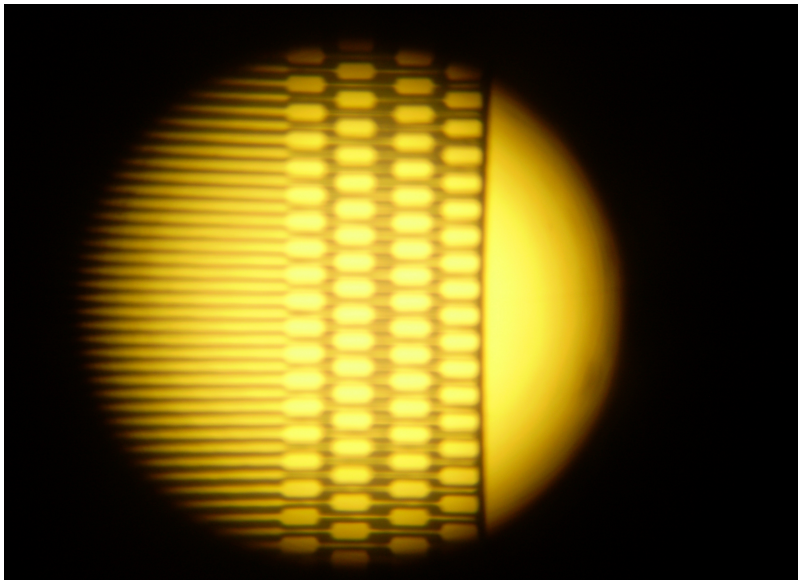


Via shadow mask

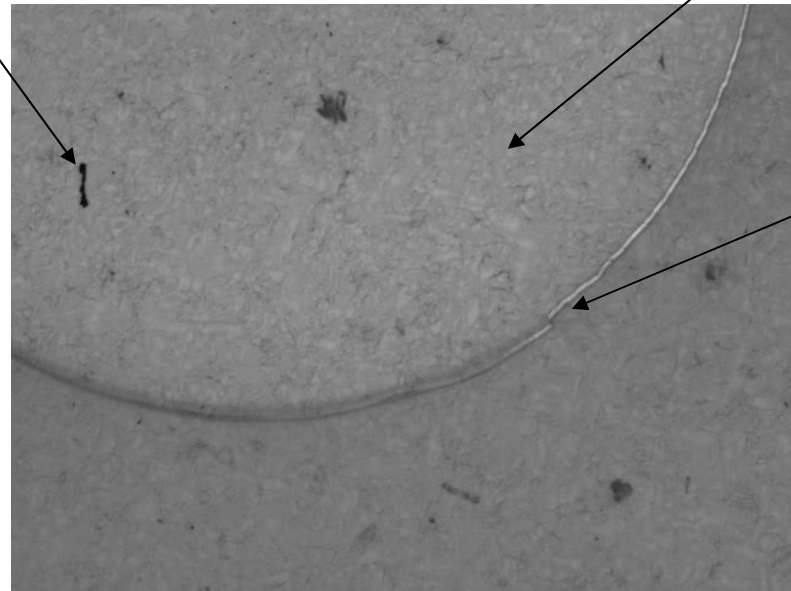


Chromium

Via photolithography

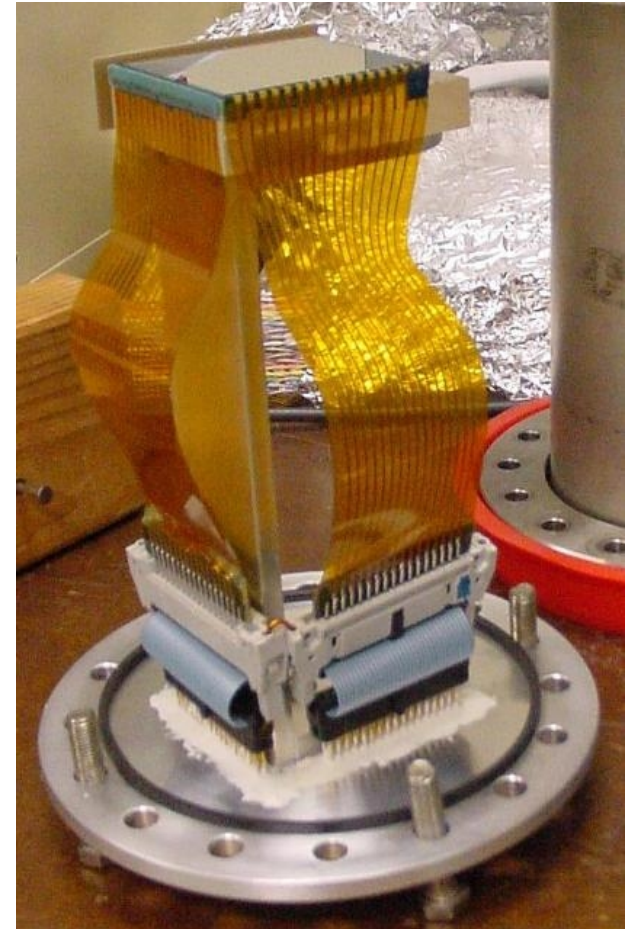
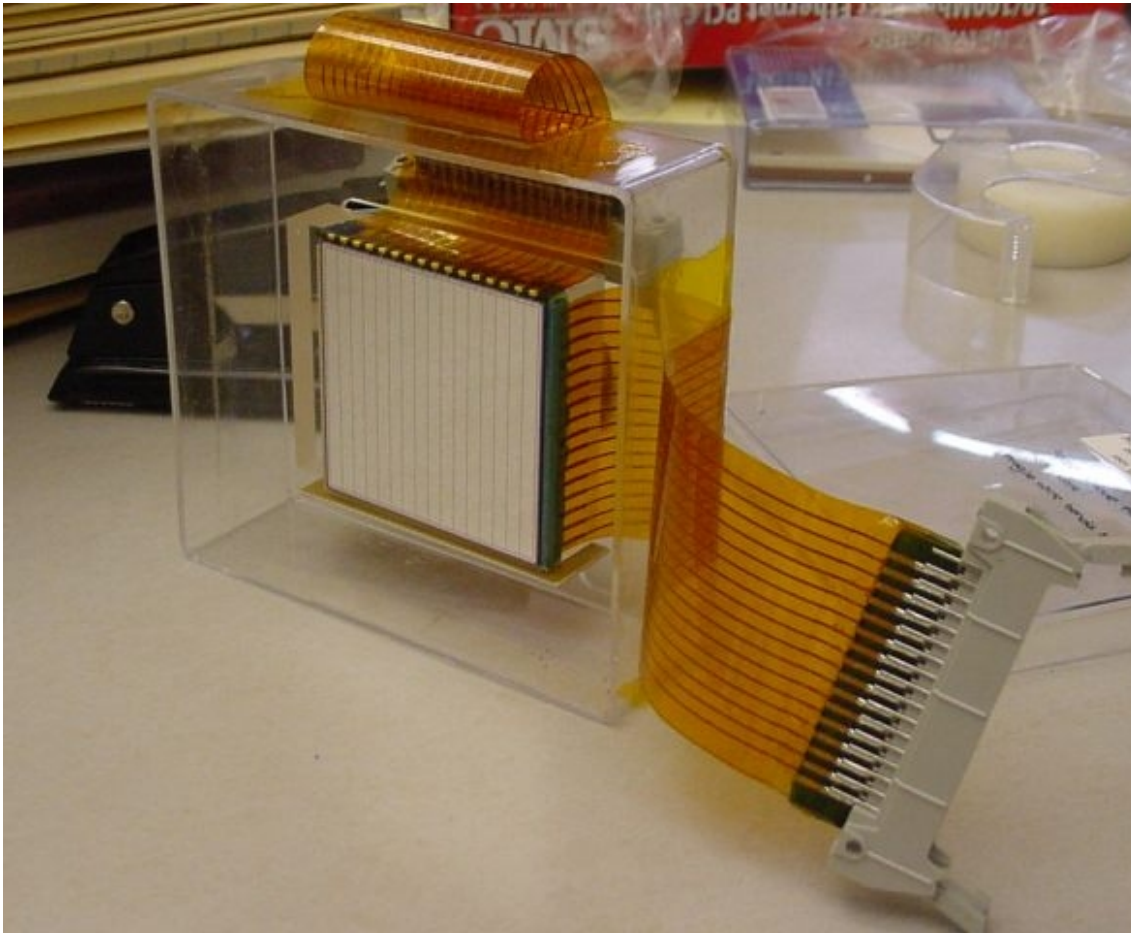


dust



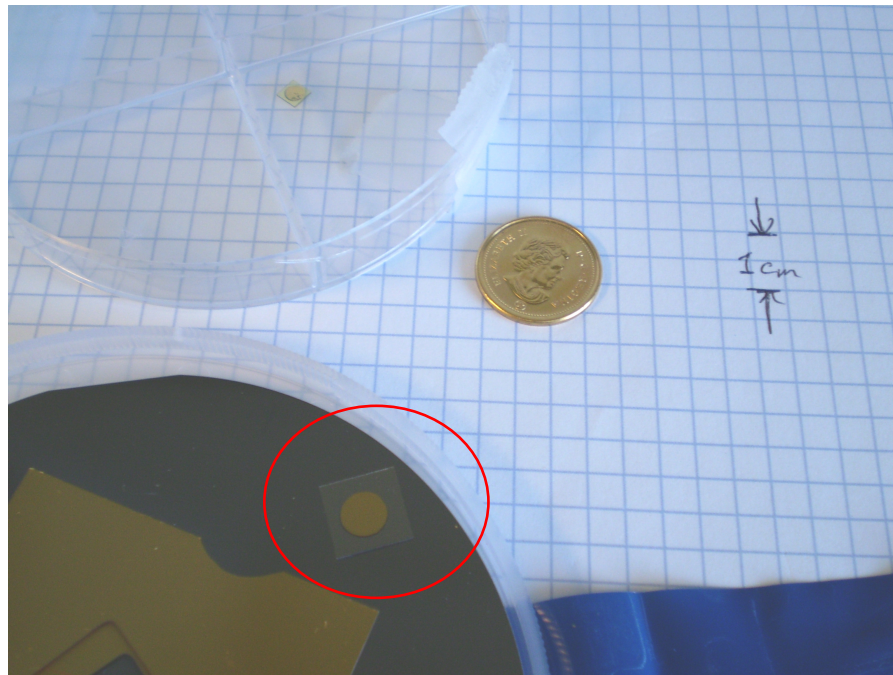
Gold

4. Mount in a nice package and wirebond



5. Check if we did good job

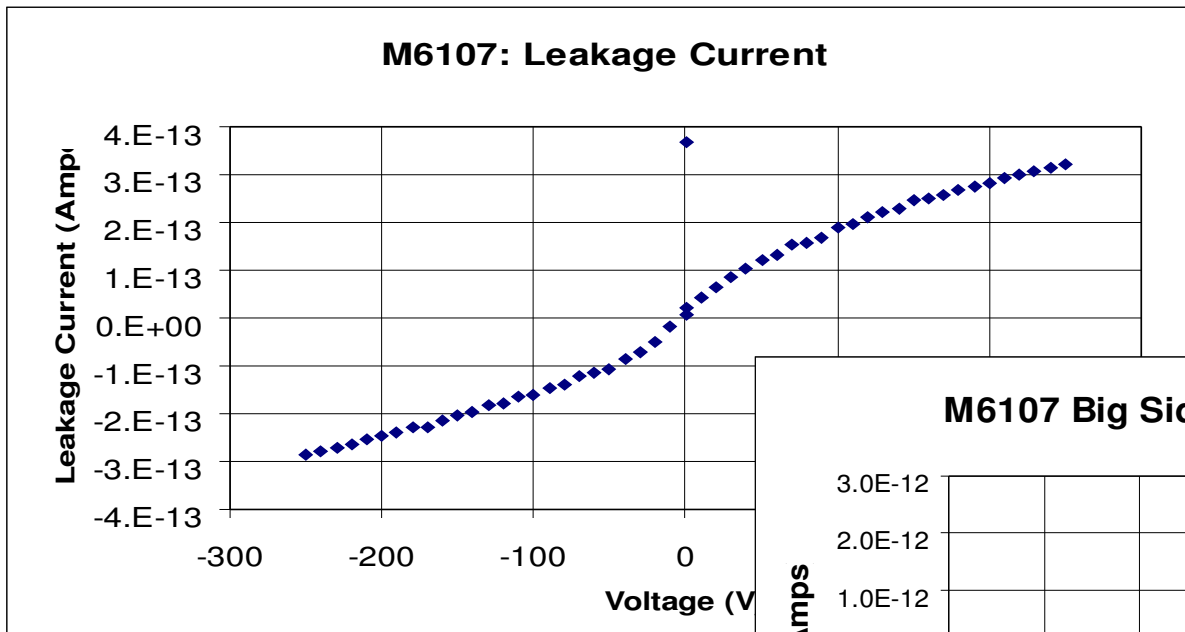
- **Tape test** - the most brutal, but gives the fastest answer
- **I-V curve** - 1 day measurement,
- Charge Collection Depth (**CCD**) measurement – 1 day measurement



I-V curve

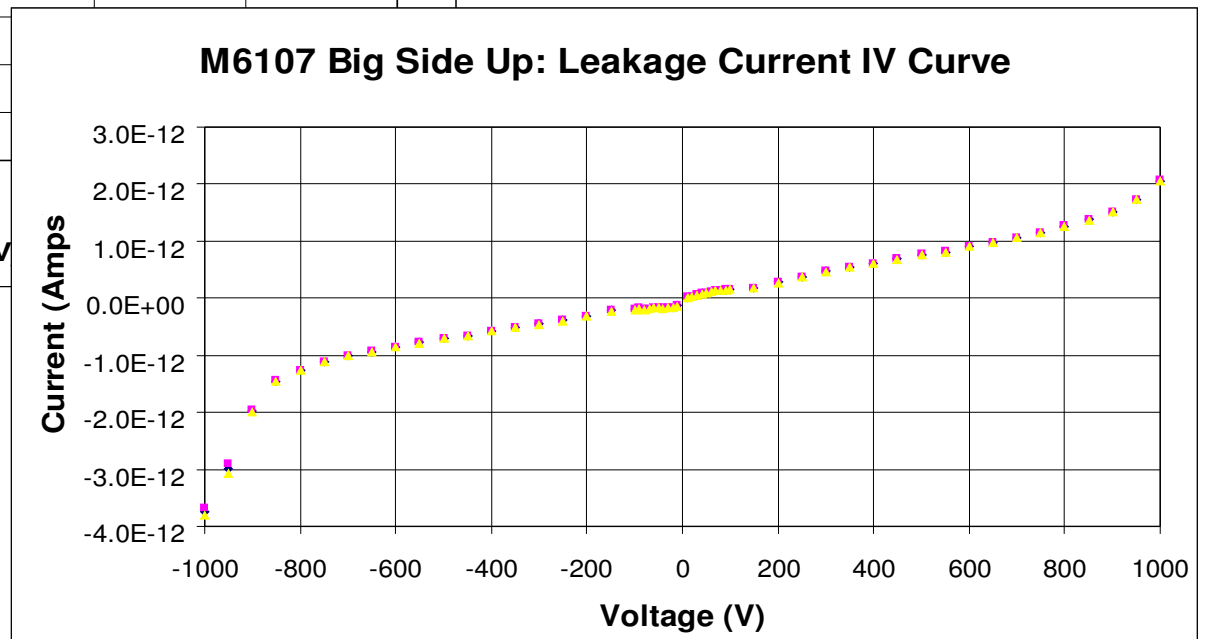
Our sample crystal 250 μ m thick, 5 x 5 mm,

Not good, contains N:



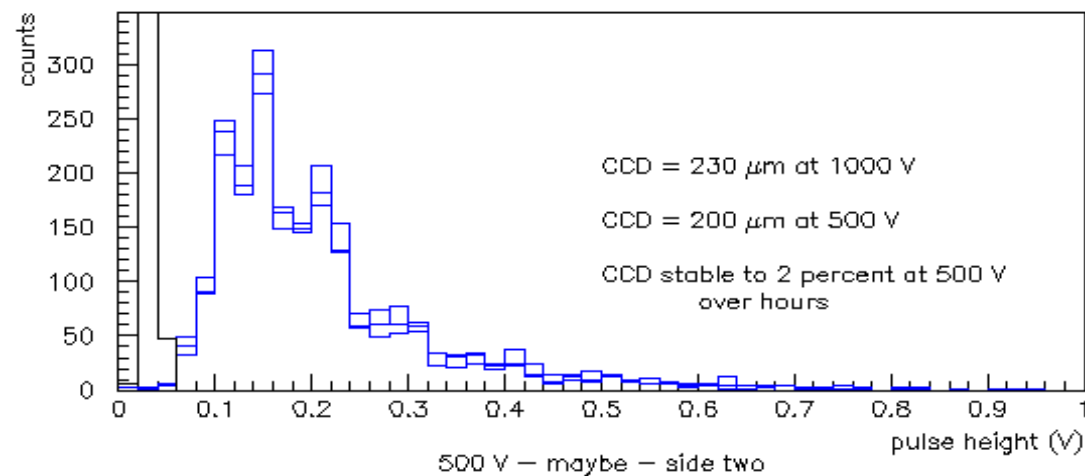
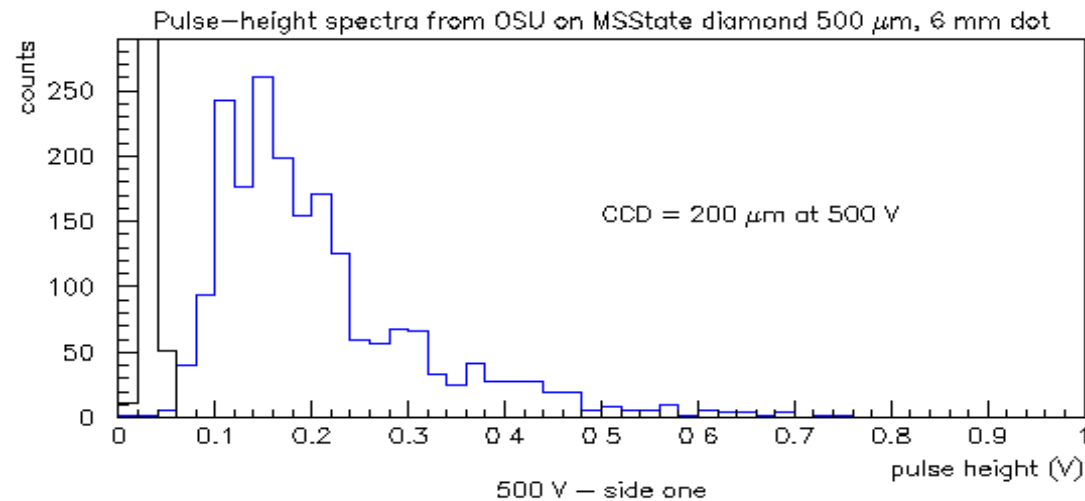
Dipangkar's diamond:

530 μ m thick, 10 x 10 mm



Charge Collection Depth (CCD) results from Dipankars's prototype diamond

Sample
thickness: 530 μm



Summary

- Coated first test diamond at NSFL (University of Manitoba EE)
- Visited Ohio State University (Harris Kagan group)
 - learned diamond preparation/metallization in context of a second diamond (D. Dutta's)
 - learned multi-strip detector fabrication
 - learned test procedures
 - CCD measurement
 - I-V curve
- Coated third diamond (hopefully did it right) at NSFL